

NP90N055MUK, NP90N055NUK MOS FIELD EFFECT TRANSISTOR

R07DS0602EJ0200 Rev.2.00 May 24, 2018

Description

These products are N-channel MOS Field Effect Transistors designed for high current switching applications.

Features

- Super low on-state resistance $R_{DS(on)} = 3.8 \text{ m}\Omega \text{ MAX.} (V_{GS} = 10 \text{ V}, I_D = 45 \text{ A})$
- Low C_{iss} : $C_{iss} = 4900 \text{ pF TYP}$. ($V_{DS} = 25 \text{ V}$)
- Designed for automotive application and AEC-Q101 qualified

Ordering Information

Part No.	Lead Plating	Packing	Package
NP90N055MUK-S18-AY *1	Pure Sn (Tin)	Tube 50 p/tube	TO-220 (MP-25K)
NP90N055NUK-S18-AY *1			TO-262 (MP-25SK)

Note: *1 Pb-free (This product does not contain Pb in the external electrode)

Absolute Maximum Ratings (T_A = 25°C)

Item	Symbol	Ratings	Unit
Drain to Source Voltage (V _{GS} = 0 V)	VDSS	55	V
Gate to Source Voltage (V _{DS} = 0 V)	V _{GSS}	±20	V
Drain Current (DC) ($T_c = 25^{\circ}C$)	I _{D(DC)}	±90	A
Drain Current (pulse) *1, 3	I _{D(pulse)}	±360	A
Total Power Dissipation ($T_c = 25^{\circ}C$)	P _{T1}	176	W
Total Power Dissipation ($T_A = 25^{\circ}C$)	P _{T2}	1.8	W
Channel Temperature	T _{ch}	175	°C
Storage Temperature	T _{stg}	–55 to 175	°C
Repetitive Avalanche Current *2, 3	lar	38	A
Repetitive Avalanche Energy *2, 3	Ear	144	mJ

Thermal Resistance

Channel to Case Thermal Resistance	R _{th(ch-C)*3}	0.85	°C/W
Channel to Ambient Thermal Resistance	Rth(ch-A) *3	83.3	°C/W

Notes: *1 T_C = 25°C, P_W \leq 10 μ s, Duty Cycle \leq 1%

*2 R_G = 25 Ω , V_{GS} = 20 \rightarrow 0 V

*3 Not subject of production test. Verified by design/characterization.



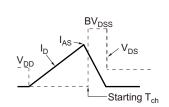
Electrical Characteristics (T_A = 25°C)

Item	Symbol	MIN.	TYP.	MAX.	Unit	Test Conditions	
Zero Gate Voltage Drain Current	I _{DSS}	—	_	1	μA	V _{DS} = 55 V, V _{GS} = 0 V	
Gate Leakage Current	I _{GSS}			±100	nA	V_{GS} = ±20 V, V_{DS} = 0 V	
Gate to Source Threshold Voltage	V _{GS(th)}	2.0	3.0	4.0	V	V_{DS} = V_{GS} , I_D = 250 μ A	
Forward Transfer Admittance *1	y _{fs}	35	70	_	S	V _{DS} = 5 V, I _D = 45 A	
Drain to Source On-state Resistance *1	R _{DS(on)}	_	3.15	3.80	mΩ	V _{GS} = 10 V, I _D = 45 A	
Input Capacitance *2	Ciss	_	4900	7350	pF	V _{DS} = 25 V	
Output Capacitance *2	Coss		500	750	pF	$V_{GS} = 0 V$	
Reverse Transfer Capacitance *2	Crss	_	180	330	pF	f = 1 MHz	
Turn-on Delay Time *2	t _{d(on)}	_	28	70	ns	V _{DD} = 28 V, I _D = 45 A	
Rise Time *2	tr		12	30	ns	V _{GS} = 10 V	
Turn-off Delay Time *2	t _{d(off)}		70	140	ns	R _G = 0 Ω	
Fall Time *2	t _f	_	7	20	ns		
Total Gate Charge *2	Q _G		80	120	nC	V _{DD} = 44 V	
Gate to Source Charge	Q _{GS}		21	_	nC	V _{GS} = 10 V	
Gate to Drain Charge	Q _{GD}		20	_	nC	I _D = 90 A	
Body Diode Forward Voltage *1	V _{F(S-D)}		0.9	1.5	V	I _F = 90 A, V _{GS} = 0 V	
Reverse Recovery Time	trr		52	_	ns	I _F = 90 A, V _{GS} = 0 V	
Reverse Recovery Charge	Qrr		95	_	nC	di/dt = 100 A/µs	

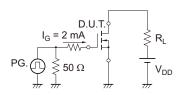
Note: *1 Pulsed test

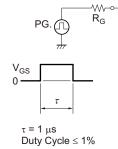
Note: *2 Not subject of production test. Verified by design/characterization.

TEST CIRCUIT 1 AVALANCHE CAPABILITY



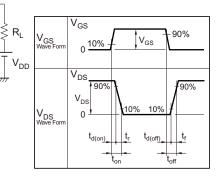
TEST CIRCUIT 3 GATE CHARGE





TEST CIRCUIT 2 SWITCHING TIME

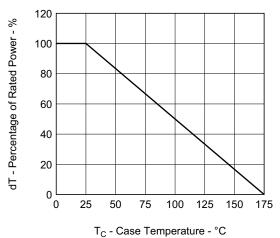
D.U.T.

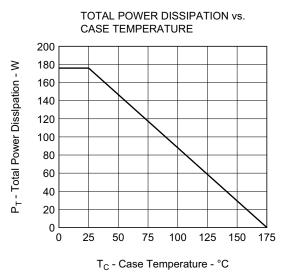




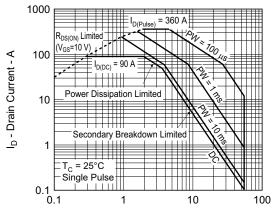
Typical Characteristics (T_A = 25°C)

DERATING FACTOR OF FORWARD BIAS SAFE OPERATING AREA



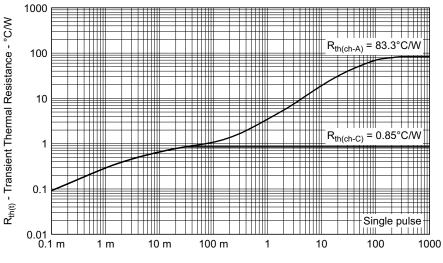


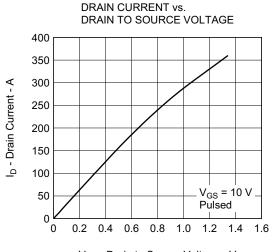
FORWARD BIAS SAFE OPERATING AREA



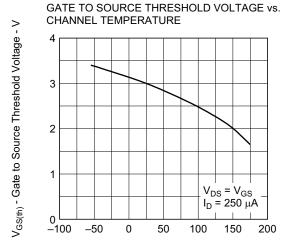


TRANSIENT THERMAL RESISTANCE vs. PULSE WIDTH



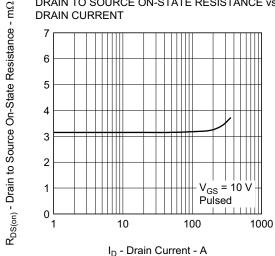


V_{DS} - Drain to Source Voltage - V

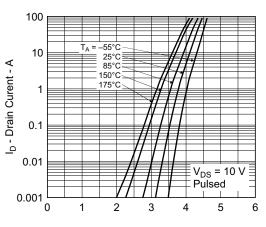


T_{ch} - Channel Temperature - °C



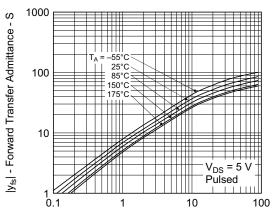


FORWARD TRANSFER CHARACTERISTICS

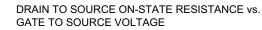


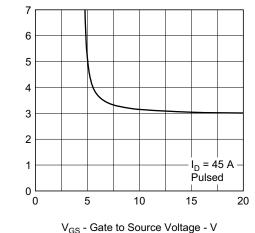


FORWARD TRANSFER ADMITTANCE vs. DRAIN CURRENT

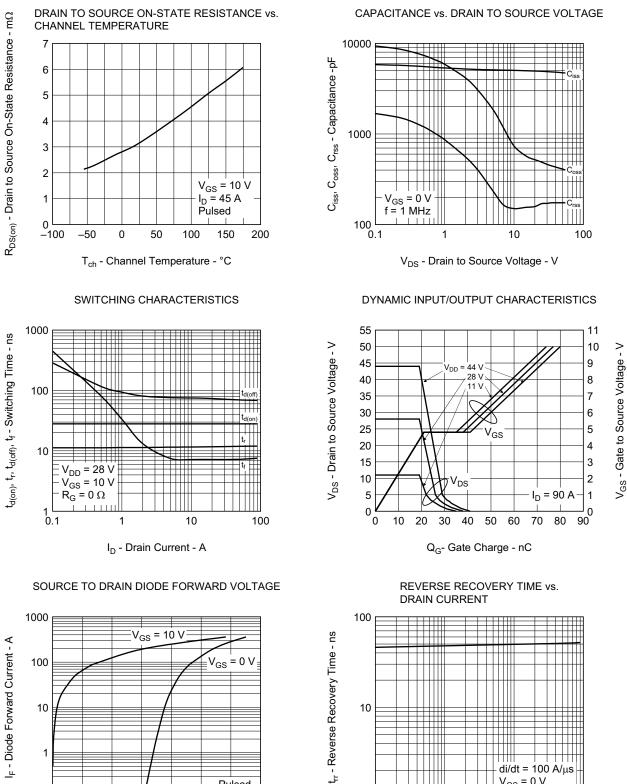


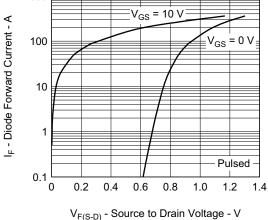
I_D - Drain Current - A





 $R_{DS(on)}$ - Drain to Source On-State Resistance - $m\Omega$





1

1 └ 0.1

10

IF - Drain Current - A

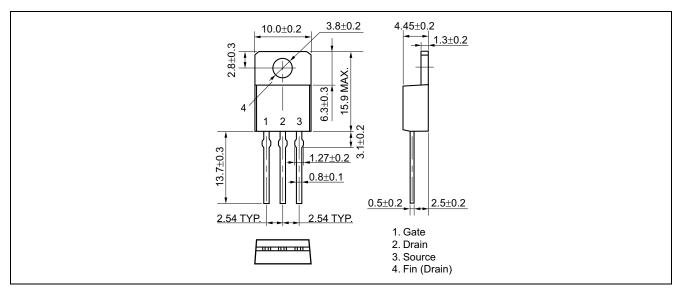
di/dt = 100 A/µs V_{GS} = 0 V

100

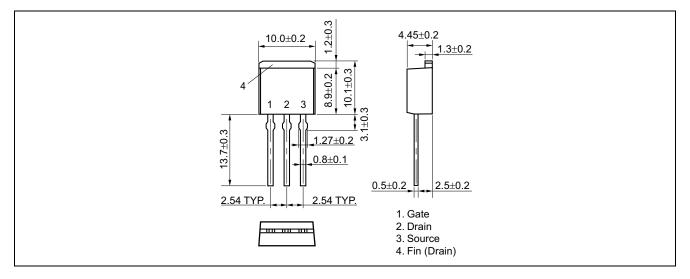


Package Drawing (Unit: mm)

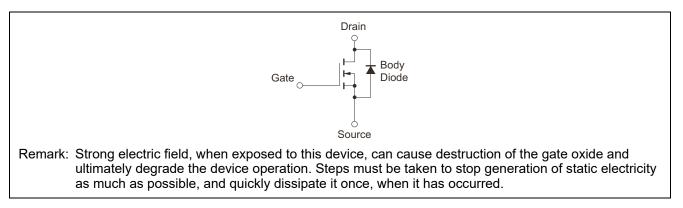
TO-220 (MP-25K) (Mass: 1.9 g TYP.)



TO-262 (MP-25SK) (Mass: 1.8 g TYP.)



Equivalent Circuit



Revision History

NP90N055MUK, NP90N055NUK Data Sheet

		Description			
Rev.	Date	Page	Summary		
1.00	Jan 11, 2012	—	First Edition Issued		
2.00	May 24 ,2018	1	Note 3 was added		
		2	Note 2 was added		

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